

Pb Free Plating Product

FES16AT thru FES16JT



16.0 Ampere Glass Passivated Super Fast Recovery Rectifier Diode

Features

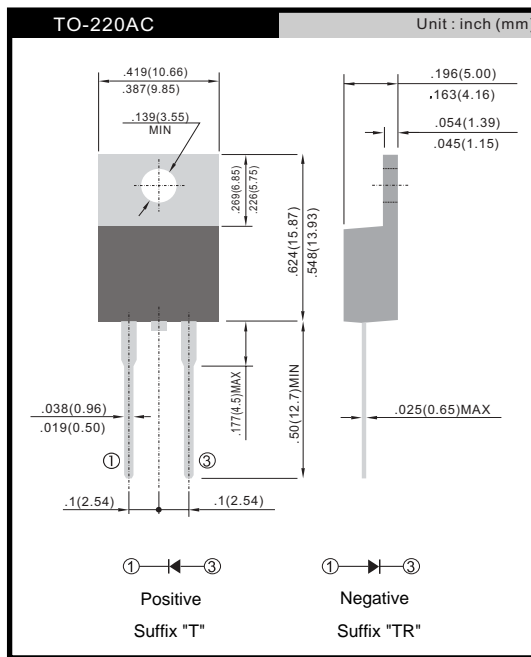
- * Glass passivated chip junction
- * Low forward voltage drop
- * High current capability
- * Low reverse leakage current
- * High surge current capability

Application

- * Automotive Inverters/Solar Inverters
- * Plating Power Supply, SMPS and UPS
- * Car Audio Amplifiers and Sound Device Systems

Mechanical Data

- * Case: Heatsink TO-220AC
- * Epoxy: UL 94V-0 rate flame retardant
- * Terminals: Solderable per MIL-STD-202 method 208
- * Polarity: As marked on diode body
- * Mounting position: Any
- * Weight: 2.1 gram approxiamtely



Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%

Type Number	Symbol	FES 16AT	FES 16BT	FES 16CT	FES 16DT	FES 16FT	FES 16GT	FES 16HT	FES 16JT	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	16								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	200								A
Maximum Instantaneous Forward Voltage (Note 1) @ 16 A	V_F	0.975			1.3		1.7			V
Maximum Reverse Current @ Rated VR $T_A=25\text{ }^\circ\text{C}$ $T_A=100\text{ }^\circ\text{C}$	I_R	10				400				uA
Maximum Reverse Recovery Time (Note 2)	T_{rr}	35								nS
Typical Junction Capacitance (Note 3)	C_j	130				100				pF
Typical Thermal Resistance	$R_{\theta JC}$	1								$^\circ\text{C/W}$
Operating Temperature Range	T_J	- 65 to + 150								$^\circ\text{C}$
Storage Temperature Range	T_{STG}	- 65 to + 150								$^\circ\text{C}$

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle
 Note 2: Reverse Recovery Test Conditions: $I_F=0.5A$, $I_R=1.0A$, $I_{RR}=0.25A$
 Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

RATINGS AND CHARACTERISTIC CURVES (FES16AT thru FES16JT)

FIG.1 FORWARD CURRENT DERATING CURVE

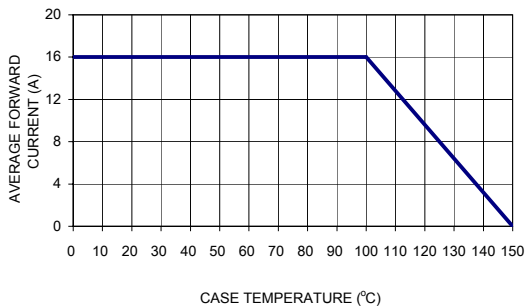


FIG. 2 TYPICAL REVERSE CHARACTERISTICS

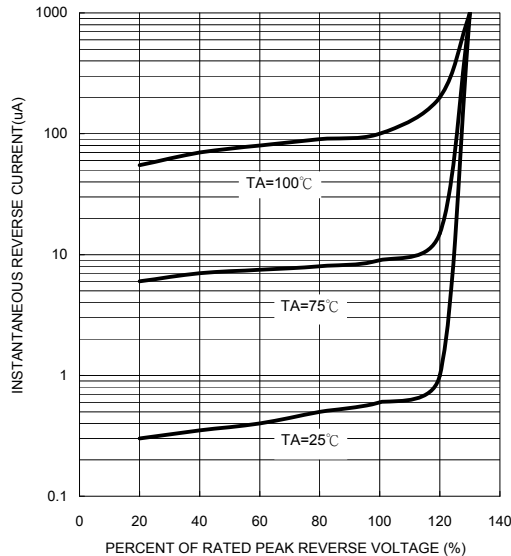


FIG. 3 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

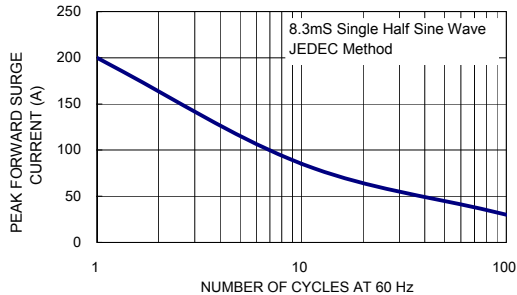


FIG. 5 TYPICAL FORWARD CHARACTERISTICS

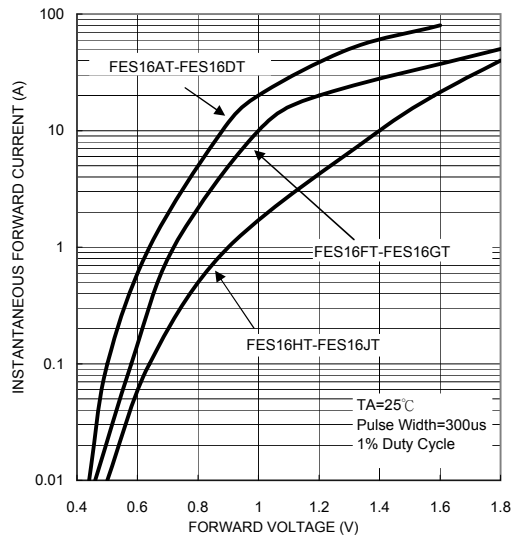


FIG. 4 TYPICAL JUNCTION CAPACITANCE

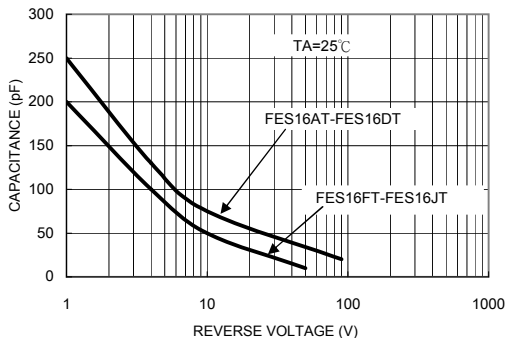


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

